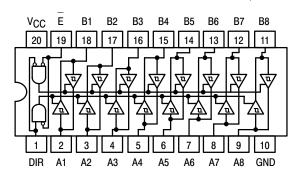
# **Octal Bus Transceiver**

The SN74LS245 is an Octal Bus Transmitter/Receiver designed for 8-line asynchronous 2-way data communication between data buses. Direction Input (DR) controls transmission of Data from bus A to bus <u>B</u> or bus B to bus A depending upon its logic level. The Enable input (E) can be used to isolate the buses.

- Hysteresis Inputs to Improve Noise Immunity
- 2-Way Asynchronous Data Bus Communication
- Input Diodes Limit High-Speed Termination Effects
- ESD > 3500 Volts

#### LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)



#### **TRUTH TABLE**

INPUTS		OUTPUT		
E	DIR	OUTPUT		
L	L	Bus B Data to Bus A		
L	Н	Bus A Data to Bus B		
Н	Χ	Isolation		

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

#### **GUARANTEED OPERATING RANGES**

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage	4.75	5.0	5.25	V
T <sub>A</sub>	Operating Ambient Temperature Range	0	25	70	°C
IОН	Output Current – High			-3.0	mA
				-15	mA
loL	Output Current – Low			24	mA



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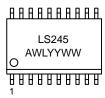
# LOW POWER SCHOTTKY

# MARKING DIAGRAMS

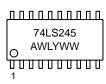












A = Assembly Location

WL = Wafer Lot YY = Year

WW = Work Week

#### **ORDERING INFORMATION**

Device	Package	Shipping	
SN74LS245N	PDIP-20	1440 Units/Box	
SN74LS245DW	SOIC-WIDE	38 Units/Rail	
SN74LS245DWR2	SOIC-WIDE	2500/Tape & Reel	
SN74LS245M	SOEIAJ-20	See Note 1.	
SN74LS245MEL	SOEIAJ-20	See Note 1.	

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

## DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

				Limits				
Symbol	Parameter		Min	Тур	Max	Unit	Те	st Conditions
VIH	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V <sub>IL</sub>	Input LOW Voltage				0.8	V	Guaranteed In All Inputs	put LOW Voltage for
$V_{T+}-V_{T-}$	Hysteresis		0.2	0.4		V	V <sub>CC</sub> = MIN	
VIK	Input Clamp Diode Vol	tage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$	
\/-··	Output HICH Voltage		2.4	3.4		V	$V_{CC} = MIN, I_{OH} = -3.0 \text{ mA}$	
VOH	Output HIGH Voltage		2.0			V	V <sub>CC</sub> = MIN, I <sub>OH</sub> = MAX	
				0.25	0.4	V	I <sub>OL</sub> = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$
VOL	Output LOW Voltage			0.35	0.5	V	I <sub>OL</sub> = 24 mA	VIN = VIL or VIH per Truth Table
lozh	Output Off Current HIC	SH			20	μΑ	V <sub>CC</sub> = MAX, \	/ <sub>OUT</sub> = 2.7 V
lozL	Output Off Current LO	W			-200	μΑ	V <sub>CC</sub> = MAX, \	/ <sub>OUT</sub> = 0.4 V
		A or B, DR or E			20	μΑ	V <sub>CC</sub> = MAX, \	/ <sub>IN</sub> = 2.7 V
lН	Input HIGH Current	DR or E			0.1	mA	V <sub>CC</sub> = MAX, \	/ <sub>IN</sub> = 7.0 V
		A or B			0.1	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 5.5 V	
I <sub>IL</sub>	Input LOW Current				-0.2	mA	V <sub>CC</sub> = MAX, \	/ <sub>IN</sub> = 0.4 V
los	Output Short Circuit Current (Note 2.)		-40		-225	mA	VCC = MAX	
	Power Supply Current Total, Output HIGH				70		V <sub>CC</sub> = MAX	
ICC	Total, Output LOW	Total, Output LOW			90	mA		
	Total at HIGH Z				95			

<sup>2.</sup> Not more than one output should be shorted at a time, nor for more than 1 second.

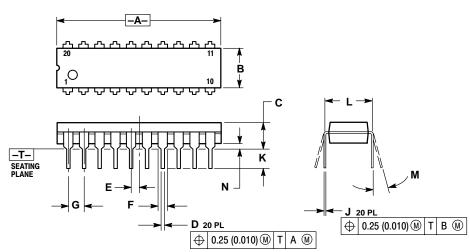
### AC CHARACTERISTICS ( $T_A = 25^{\circ}C$ , $V_{CC} = 5.0 \text{ V}$ , $T_{RISE}/T_{FALL} \le 6.0 \text{ ns}$ )

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay, Data to Output		8.0 8.0	12 12	ns	C <sub>L</sub> = 45 pF,	
<sup>t</sup> PZH	Output Enable Time to HIGH Level		25	40	ns	$R_L = 667 \Omega$	
<sup>t</sup> PZL	Output Enable Time to LOW Level		27	40	ns		
<sup>t</sup> PLZ	Output Disable Time from LOW Level		15	25	ns	C <sub>L</sub> = 5.0 pF,	
<sup>t</sup> PHZ	Output Disable Time from HIGH Level		15	25	ns	$C_L = 5.0 \text{ pF},$ $R_L = 667 \Omega$	

#### **PACKAGE DIMENSIONS**

#### **N SUFFIX**

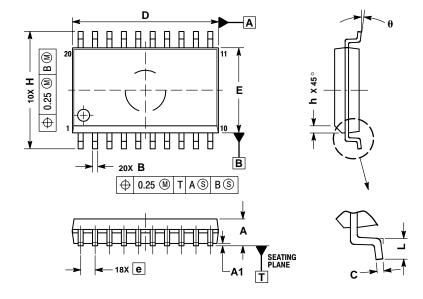
PLASTIC PACKAGE CASE 738-03 ISSUE E



- IOLES:
  1 DIMENSIONING AND TOLERANCING PER ANSI
  Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEAD WHEN
  FORMED PARALLEL.
  4. DIMENSION B DOES NOT INCLUDE MOLD
- FLASH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.010	1.070	25.66	27.17	
В	0.240	0.260	6.10	6.60	
С	0.150	0.180	3.81	4.57	
D	0.015	0.022	0.39	0.55	
Е	0.050	BSC	1.27 BSC		
F	0.050	0.070	1.27	1.77	
G	0.100	BSC	2.54 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.140	2.80	3.55	
L	0.300 BSC		7.62	BSC	
M	0 °	15°	0°	15°	
N	0.020	0.040	0.51	1.01	

#### **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751D-05 ISSUE F



- NOTES:

  1. DIMENSIONS ARE IN MILLIMETERS.
  2. INTERPRET DIMENSIONS AND TOLERANCES
  PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.

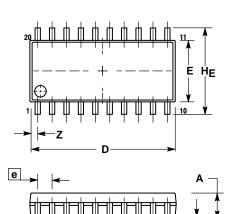
  MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10	0.25		
В	0.35	0.49		
С	0.23	0.32		
D	12.65	12.95		
Е	7.40	7.60		
е	1.27	BSC		
Н	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
A	n o	70		

#### PACKAGE DIMENSIONS

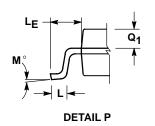
#### **M SUFFIX**

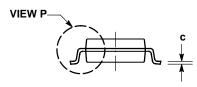
SOEIAJ PACKAGE CASE 967-01 **ISSUE O** 



0.10 (0.004)

0.13 (0.005) M





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD
  FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE, MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
- TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
  THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH
  DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT, MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α		2.05		0.081	
Α <sub>1</sub>	0.05	0.20	0.002	0.008	
b	0.35	0.50	0.014	0.020	
C	0.18	0.27	0.007	0.011	
D	12.35	12.80	0.486	0.504	
Е	5.10	5.45	0.201	0.215	
е	1.27 BSC		0.050 BSC		
ΗE	7.40	8.20	0.291	0.323	
L	0.50	0.85	0.020	0.033	
LF	1.10	1.50	0.043	0.059	
M	0 °	10°	0 °	10°	
Q <sub>1</sub>	0.70	0.90	0.028	0.035	
Z		0.81		0.032	

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